

Kidist Moges

List of Publications by Citations

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

4

papers

29

citations

3

h-index

5

g-index

5

ext. papers

39

ext. citations

2.3

avg, IF

1.43

L-index

#	Paper	IF	Citations
4	Passive/Active oxidation boundary for thermal oxidation of 4H-SiC(0001) surface in O ₂ /Ar gas mixture and its impact on SiO ₂ /SiC interface quality. <i>Applied Physics Express</i> , 2018 , 11, 091301	2.4	13
3	Sub-nanometer-scale depth profiling of nitrogen atoms in SiO ₂ /4H-SiC structures treated with NO annealing. <i>Applied Physics Express</i> , 2018 , 11, 101303	2.4	9
2	Performance improvement in 4H-SiC(0001) p-channel metal-oxide-semiconductor field-effect transistors with a gate oxide grown at ultrahigh temperature. <i>Applied Physics Express</i> , 2019 , 12, 061003	2.4	6
1	Demonstration of 4H-SiC CMOS circuits consisting of well-balanced n- and p-channel MOSFETs fabricated by ultrahigh-temperature gate oxidation. <i>Applied Physics Express</i> , 2021 , 14, 091006	2.4	1